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Nanoscale Electrochemical charge transfer kinetics investigated by Electrochemical Scanning Microwave Microscopy.

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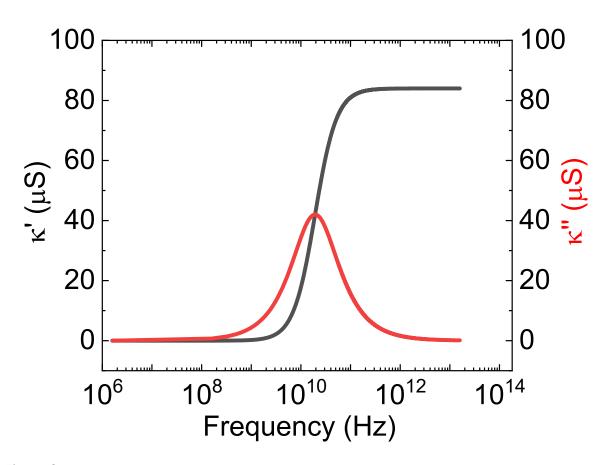


Figure S1 The complex conductance against high frequency. The black line is the real part of conductance $\dot{\kappa}$, the value of $\dot{\kappa}^{\kappa}$ increases at $1/\tau \ll \omega$. The red line is the imaginary part of the complex conductance $\dot{\kappa}^{\kappa}$, the value $\ddot{\kappa}^{\kappa}$ is $\simeq 0$ at $1/\tau \ll \omega$

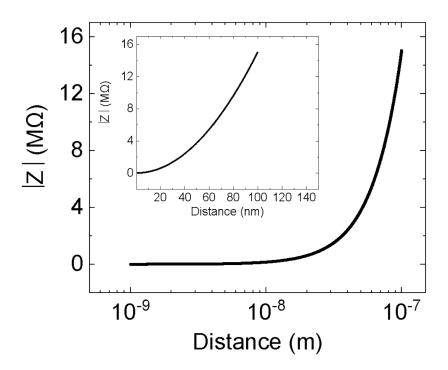


Figure S2 solution impedance at different tip-sample distances. The impedance rapidly increases at D at <100nm using equation 1.

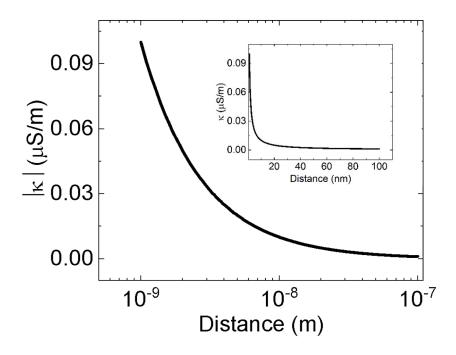


Figure S3 shows how the conductance decays as the distance increases: the conductance rapidly decreases at D at <100nm using equation 9

Supplementary Note 1. tip capacitance and radius

The measured current is proportional with area therefore:

$$\frac{I_G}{A_G} = \frac{I_L}{A_L}$$

Where I_G and A_G are the current of global CV and the whole area of the sample, I_L and A_L are the current of local CV and the area of the tip.

$$\frac{0.6 \times 10^{-6} A}{0 \cdot 25 cm^2} = \frac{16 \times 10^{-18} A}{A_L}$$

$$A_L = \frac{16 \times 10^{-18} A \times 0.25 cm^2}{0.6 \times 10^{-6} A} = 6.66 \times 10^{-12} cm^2 = 666 \pm 110 nm^2$$

$$A = \pi r^2 = 666 \pm 110 nm^2$$

$$r = 14 \pm 2 nm$$

$$\frac{3 (aA)}{666 (nm^2) \times 0.01 (\frac{V}{s})} = 45 \mu E/cm^2$$

$$C_{p} = \frac{666 (nm^{2}) \times 0.01(-)}{s} 45 \,\mu\text{F}/cn}{s}$$

$$C = \frac{\varepsilon A}{d}$$

Where is d=0.1 nm, A=666 nm^2

$$\varepsilon = \frac{0.1 \times 10^{-9} \, m \, \times 45 \times 10^{-10} \, F}{666 x^{10^{-9}} m^2} = 0.675 \, \text{pF/m}$$

Supplementary Note 2. Conductance change due to the increase of charge concentration

$$Z_{tot} = Z_{sol} + Z_{SAM} = L/(\kappa' + i\kappa'')A$$

$$Re(z) = d/(\kappa' + i\kappa'')A$$

$$Q_{ions} = Q_f(1 - \frac{Z_{SAM}}{Z_{tot}})$$

Where Z_{SAM} can be approximated to a parallel plate capacitor $C_{SAM} = \frac{\varepsilon_o \varepsilon_{rA}}{d}$

$$\begin{aligned} \kappa_{\infty} &= \frac{c_{ions}}{c_{water}} \kappa_{\infty,water} = \frac{Q_{ions}}{F \, A \, L \, c_{w}} \kappa_{\infty,w} = \frac{\kappa_{\infty,w}}{F \, A \, L \, c_{w}} Q_{ions} = \frac{\kappa_{\infty,w}}{F \, A \, L \, c_{w}} Q_{f} (1 - \frac{Z_{SAM}}{Z_{tot}}) \\ \kappa_{\infty} &= \frac{Q_{f} \times \kappa_{\infty,w}}{F \, A \, L \, c_{w}} \left(\frac{Z_{tot} - Z_{SAM}}{Z_{tot}} \right)_{=} \frac{Q_{f} \times \kappa_{\infty,w}}{F \, A \, L \, c_{w}} \left(\frac{Z_{sol}}{Z_{sol}} \right)_{=} \frac{Q_{f} \times \kappa'_{\infty,w}}{F \, A \, L \, c_{w}} \left(\frac{Z_{sol}}{Z_{sol} + Z_{SAM}} \right) \\ z &= \frac{1}{j\omega C} = \frac{1}{\frac{1}{j\omega C}} = \frac{1}{\frac{1}{\omega \varepsilon A}} \frac{d}{d} = \frac{d}{\omega \varepsilon A} \\ \kappa_{\infty} &= \frac{Q_{f} \times \kappa'_{\infty,w}}{F \, LA \, c_{w}} \left(\frac{\left(\frac{L}{\frac{1}{\omega \omega A \varepsilon_{w}}}\right)}{\left(\frac{1}{\omega \omega A \varepsilon_{w}}\right) + \left(\frac{1}{\frac{1}{\omega} \omega A \varepsilon_{SAM}}\right)} \right)_{=} \frac{Q_{f} \times \kappa'_{\infty,w}}{F \, LA \, c_{w}} \left(\frac{\left(\frac{L}{\varepsilon_{w}}\right)}{\left(\frac{L}{\varepsilon_{w}}\right)} \right) \\ \kappa_{\infty} &= \frac{Q_{f} \times \kappa'_{\infty,w}}{F \, LA \, c_{w}} \left(\frac{\left(\frac{L}{\varepsilon_{sAM}}\right)}{\left(\frac{\varepsilon_{sAM}}{\varepsilon_{sAM}}\right) + \left(\frac{\varepsilon_{w}^{*}h}{\varepsilon_{w}^{*}\varepsilon_{sAM}^{*}}\right)} \right)_{=} \frac{Q_{f} \times \kappa'_{\infty,w}}{F \, LA \, c_{w}} \left(\frac{\left(\frac{L}{\varepsilon_{w}}\right)}{\left(\frac{\varepsilon_{sAM}}{\varepsilon_{sAM}} + \varepsilon_{w}h}\right)} \right) \\ \end{array}$$

 $\kappa_{\infty} = \frac{Q_f \times \kappa_{\infty,w}}{F A c_w} \left(\frac{\varepsilon_{SAM}}{\varepsilon_{SAM} L + \varepsilon_w h} \right)$